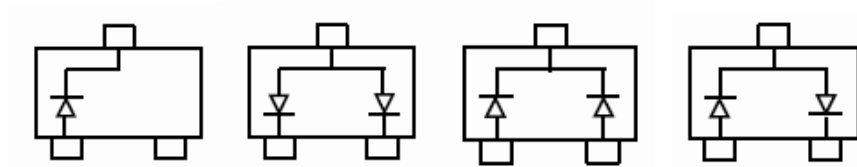
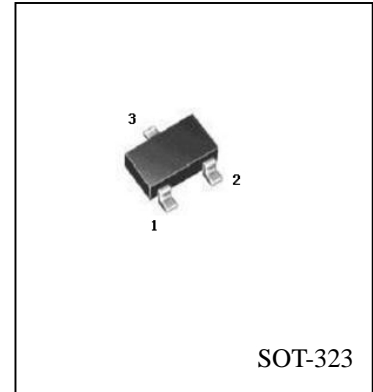


## BAT54W/AW/CW/SW

### FEATURES

- Extremely Fast Switching Speed
- Low forward voltage



BAT54W : KL5

BAT54AW : KL6

BAT54CW : KL 7

BAT54SW : KL8

### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted )

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	30	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Blocking Voltage	$V_R$		
Forward Continuous Current	$I_{FM}$	200	mA
Non-repetitive Peak Forward Surge Current @ $t < 1\text{s}$	$I_{FSM}$	600	mA
Repetitive Peak Forward Current @ $t \leq 1\text{s}, \delta \leq 0.5$	$I_{FRM}$	300	mA
Power Dissipation	$P_D$	200	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	500	$^{\circ}\text{C}/\text{W}$
Junction Temperature	$T_j$	125	$^{\circ}\text{C}$
Storage Temperature	$T_{stg}$	-55~+150	$^{\circ}\text{C}$

### ELECTRICAL CHARACTERISTICS( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	30			V
Reverse current	$I_R$	$V_R=25\text{V}$			2	$\mu\text{A}$
Forward voltage	$V_F$	$I_{F1}=0.1\text{mA}$			0.24	V
		$I_{F2}=1\text{mA}$			0.32	V
		$I_{F3}=10\text{mA}$			0.40	V
		$I_{F4}=30\text{mA}$			0.50	V
		$I_{F5}=100\text{mA}$			1	V
Diode capacitance	$C_D$	$V_R=0\text{V}, f=1\text{MHz}$			10	pF
Reverse recovery time	$t_{rr}$	$I_F=I_R=10\text{mA}$ $I_{rr}=0.1 \times I_R, R_L=100\Omega$			5	ns

## BAT54W/AW/CW/SW

